

TECHNICAL DATA DATA SHEET 5084, REV. –

# **Standard Recovery Rectifier**

- Hermetic, non-cavity glass package
- Metallurgically bonded
- Operating and Storage Temperature: -65°C to +175°C

TYPE NUMBER	PEAK INVERSE VOLTAGE	MAX. AVG. DC OUTPUT CURRENT	REVI CURI	MUM ERSE RENT PIV	MAX. PEAK FORWARD VOLTAGE (PULSED)		PEAK 1 CYCLE SURGE CURRENT	MAXIMUM REVERSE RECOVERY TIME	THERM. RESIS. R <sub>0</sub> JL d=.375"
		Amps	μAmps						
	Volts	55°C	25°C	150°C	V	Α	Amps	nsec	°C/W
SS4245/US	200								
SS4246/US	400								
SS4247/US	600	1.0	1.0	150	1.3	3.0	25	5000	42
SS4248/US	800								
SS4249/US	1000								

<sup>• 221</sup> West Industry Court 🗉 Deer Park, NY 11729-4681 🖺 Phone (631) 586 7600 Fax (631) 242 9798 •

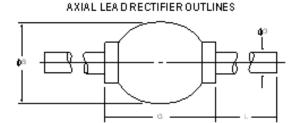
<sup>•</sup> World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •



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# MECHANICAL DIMENSIONS In Inches / (mm)

### **AXIAL**

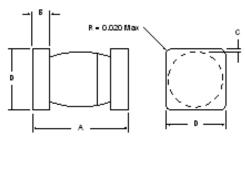


Note: Cathode side of device is indicated by a dark band marked on body.

PACKAGE STYLE	DIMENSIONS - INCHES / MILLIMETERS						
	Æe	$\phi_{\mathbb{D}}$	G	L			
103	.065/.150	.027/.033	.140/.250	1.0/1.50			
	1.65/3.81	.69/.84	3.56/6.35	25.4/38.1			

### **MELF**

## MELF PACKAGE OUTLINES



Note: Cathode side of device is indicated by a dark band marked on body.

PACKAGE STYLE	DIMENSIONS - INCHES / MILLIMETERS						
	Α	В	С	D			
MELF-1	.168/.230	0.019/.028	.003 Min	.091/.128			
	4 2/5 9	48772	076 Min	2 311/3 251			



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